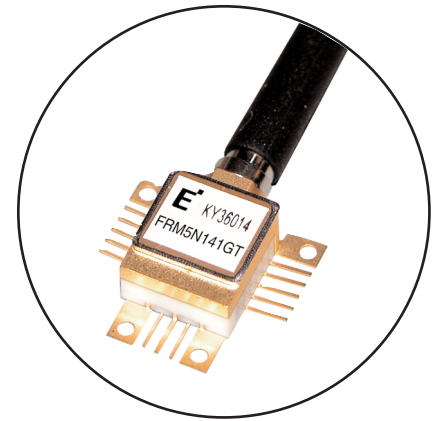


FEATURES

- Board mount type “GT” package: 17 pins
- InGaAs-APD with pre-amplifier
- Integrated Design Optimizes Performance at Bit Rates up to 10.7Gb/s
- Electrical Differential Output
- High Sensitivity: -26.5dBm
- Operates in both C and L wavelength bands



APPLICATIONS

This APD with preamplifier is intended to function as an optical receiver at 1,310nm or 1,530-1,610nm in SONET, SDH, DWDM or other optical fiber systems operating up to 10.7Gb/s. The typical transimpedance (Z_t) value of 1,200 Ω optimizes the total bandwidth for 10Gb/s application. The detector preamplifier is DC coupled and has an electrical differential output.

DESCRIPTION

The FRM5N141GT incorporates a high bandwidth InGaAs APD photo diode, a GaAs amplifier in a hermetically sealed board mount type package. The APD is processed with modern epitaxial techniques resulting in a reliable performance over a wide range of operating conditions.

ABSOLUTE MAXIMUM RATINGS ($T_c=25^\circ\text{C}$, unless otherwise specified)

Parameter	Symbol	Ratings		Unit
		Min.	Max.	
Storage Temperature	T_{stg}	-40	+85	$^\circ\text{C}$
Operating Temperature	T_{op}	-5	+75	$^\circ\text{C}$
Supply Voltage	V_{ss}	-6	0	V
APD Reverse Voltage	V_R	0	$V_B(\text{Note})$	V
APD Reverse Current	I_R	-	4(peak)	mA

Note: Since V_B may vary from device-to-device, V_B data is attached to each device for reference.

OPTICAL & ELECTRICAL CHARACTERISTICS

(T_C=25°C, λ=1,550nm, V_{SS}=-5.2V, unless otherwise specified)

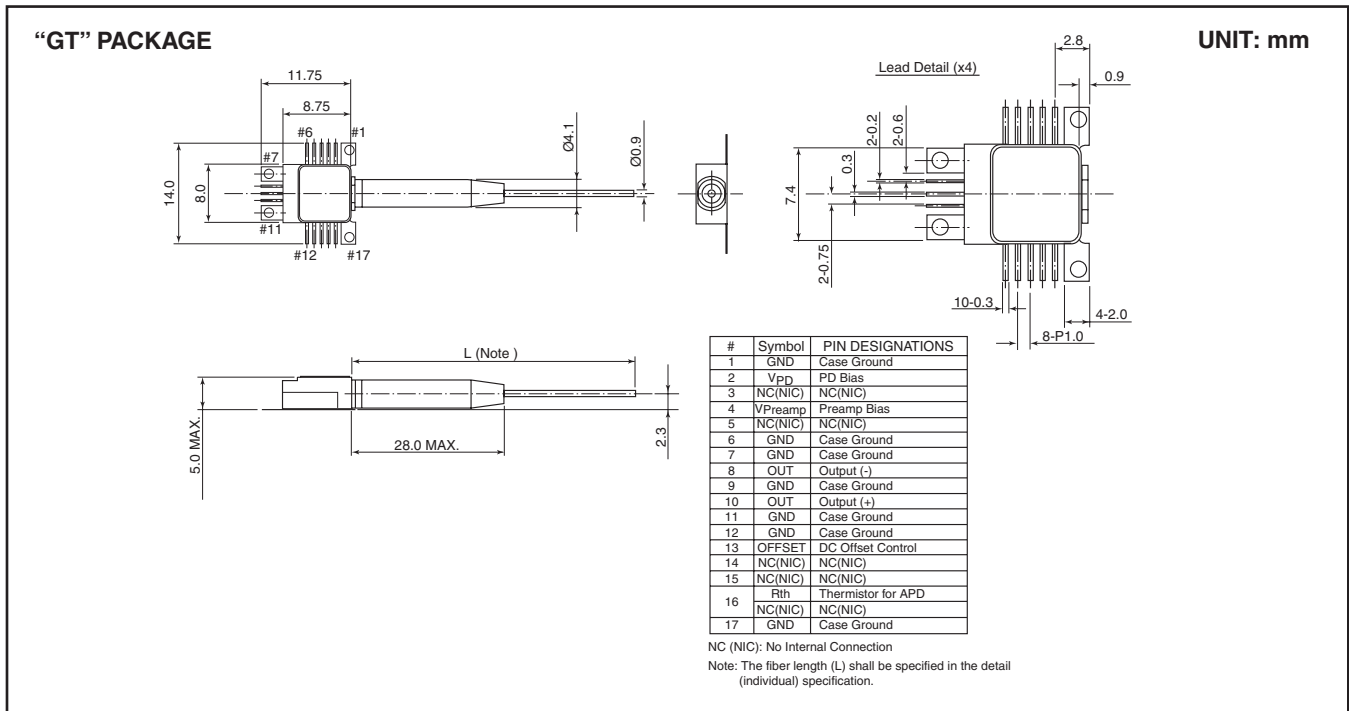
Parameter	Symbol	Test Conditions	Limits			Unit	
			Min.	Typ.	Max.		
APD Responsivity	R	λ = 1,310nm, M=1	0.75	0.85	-	A/W	
		λ = 1,550nm, M=1	0.75	0.90	-		
		λ = 1,610nm, M=1	-	0.80	-		
APD Breakdown Voltage	VB	ID = 10μA	20.0	25.0	30.0	V	
Temperature Coefficient of VB	Γ	Note (1)	0.03	0.05	0.07	V/°C	
AC Transimpedance	Z _t	f = 750MHz, Single-end	800	1200	-	Ω	
Maximum Output Voltage Swing	V _{clip}	Saturated Output Voltage	350	550	750	mV	
Bandwidth	BW	-3dB from 750MHz, Pin=-20dBm	M=9	6.0	7.5	8.5	GHz
			M=3	6.0	7.5	-	
Lower Cut-off Frequency	f _{cl}	-3dB from 750MHz, Pin=-20dBm	-	40	100	kHz	
Peaking	d _{pk}	130MHz to BW, Pin=-20dBm, M=9	-	0.5	-	dB	
Group Delay Deviation	GD	1GHz to 4GHz, Pin=-20dBm, M=9	-	30	-	ps _{p-p}	
		1GHz to 6GHz, Pin=-20dBm, M=9	-	50	-		
Output Return Loss	S ₂₂	130MHz to 6GHz	-	12	-	dB	
		130MHz to 8GHz	-	7	-		
Minimum Sensitivity	P _r	10Gb/s, NRZ, PRBS=2 ³¹ -1, B.E.R.=10 ⁻¹² , VR=Optimum, Rext=13dB	25°C	-	-26.5	-25.0	dBm
			75°C	-	-25.5	-24.0	
Maximum Overload	P _o	10Gb/s, NRZ, PRBS=2 ³¹ -1, B.E.R.=10 ⁻¹² , M=3, Rext=13dB	-7	-5	-	dBm	
Optical Return Loss	ORL	λ = 1,550nm	27	-	-	dB	
		λ = 1,310nm	27	-	-		
Power Supply Current	I _{ss}	-	-	110	130	mA	
Power Supply Voltage	V _{ss}	-	-5.46	-5.20	-4.94	V	
Thermistor Resistance	R _{th}	-	9.5	10.0	10.5	kΩ	
Thermistor B Constant	B	-	3800	3900	4000	K	

Note 1: Γ=ΔVB/dTc

Note: All the parameters are measured with 50Ω load through external coupling capacitor.

Notes

www.DataSheet4U.com



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